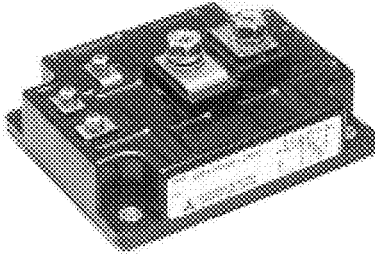


QM400HA-2HB

HIGH POWER SWITCHING USE
INSULATED TYPE

QM400HA-2HB



- **I_C** Collector current **400A**
- **V_{CEX}** Collector-emitter voltage **1000V**
- **h_{FE}** DC current gain..... **750**
- **Insulated Type**
- **UL Recognized**

Yellow Card No. E80276 (N)

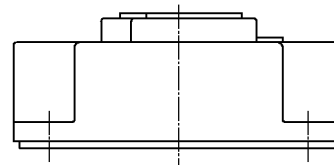
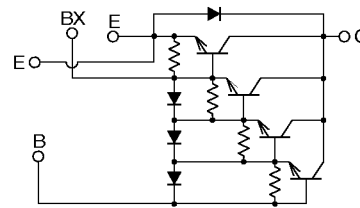
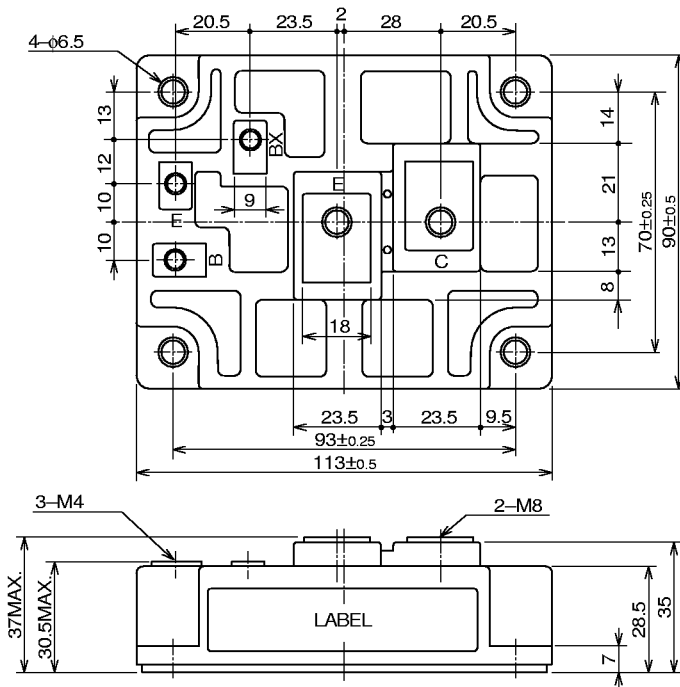
File No. E80271

APPLICATION

AC motor controllers, UPS, CVCF, DC motor controllers, NC equipment, Welders

OUTLINE DRAWING & CIRCUIT DIAGRAM

Dimensions in mm



QM400HA-2HB

HIGH POWER SWITCHING USE
INSULATED TYPE

ABSOLUTE MAXIMUM RATINGS (T_J=25°C, unless otherwise noted)

Symbol	Parameter	Conditions	Ratings	Unit
V _{CE(SUS)}	Collector-emitter voltage	I _C =1A, V _{EB} =2V	1000	V
V _{CEX}	Collector-emitter voltage	V _{EB} =2V	1000	V
V _{CB0}	Collector-base voltage	Emitter open	1000	V
V _{EB0}	Emitter-base voltage	Collector open	7	V
I _C	Collector current	DC	400	A
-I _C	Collector reverse current	DC (forward diode current)	400	A
P _C	Collector dissipation	T _C =25°C	3120	W
I _B	Base current	DC	20	A
-I _{CSM}	Surge collector reverse current (forward diode current)	Peak value of one cycle of 60Hz (half wave)	4000	A
T _J	Junction temperature		-40~+150	°C
T _{slg}	Storage temperature		-40~+125	°C
V _{iso}	Isolation voltage	Charged part to case, AC for 1 minute	2500	V
—	Mounting torque	Main terminal screw M8	8.83~10.8	N·m
			90~110	kg·cm
		Mounting screw M6	1.96~2.94	N·m
			20~30	kg·cm
		B(E) terminal screw M4	0.98~1.47	N·m
			10~15	kg·cm
		BX terminal screw M4	0.98~1.47	N·m
			10~15	kg·cm
—	Weight	Typical value	870	g

ELECTRICAL CHARACTERISTICS (T_J=25°C, unless otherwise noted)

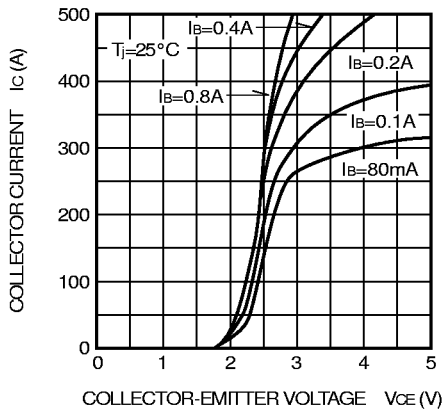
Symbol	Parameter	Test conditions	Limits			Unit
			Min.	Typ.	Max.	
I _{CEX}	Collector cutoff current	V _{CE} =1000V, V _{EB} =2V	—	—	6.0	mA
I _{CB0}	Collector cutoff current	V _{CB} =1000V, Emitter open	—	—	6.0	mA
I _{EB0}	Emitter cutoff current	V _{EB} =7V, Collector open	—	—	300	mA
V _{CE(sat)}	Collector-emitter saturation voltage	I _C =400A, I _B =530mA	—	—	4.0	V
V _{BE(sat)}	Base-emitter saturation voltage		—	—	4.0	V
-V _{CEO}	Collector-emitter reverse voltage	I _C =-400A (diode forward voltage)	—	—	1.8	V
h _{FE}	DC current gain	I _C =400A, V _{CE} =4.0V	750	—	—	—
t _{on}	Switching time	V _{CC} =600V, I _C =400A, I _{B1} =800mA, -I _{B2} =8.0A	—	—	2.5	μs
t _s			—	—	15	μs
t _f			—	—	3.0	μs
R _{th(j-c)Q}	Thermal resistance (junction to case)	Transistor part	—	—	0.04	°C/W
R _{th(j-c)R}		Diode part	—	—	0.175	°C/W
R _{th(c-f)}	Contact thermal resistance (case to fin)	Conductive grease applied	—	—	0.02	°C/W

QM400HA-2HB

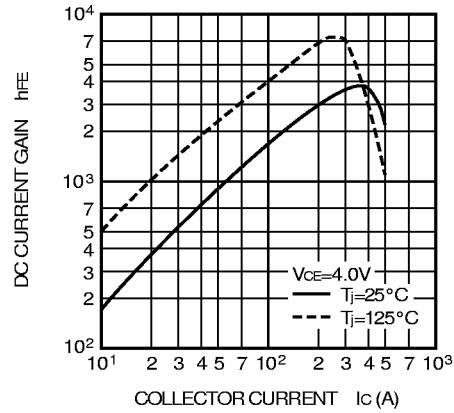
HIGH POWER SWITCHING USE
INSULATED TYPE

PERFORMANCE CURVES

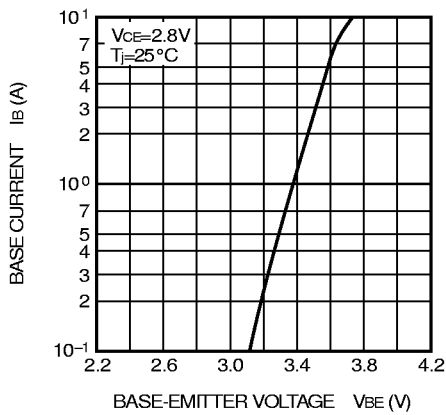
COMMON EMITTER OUTPUT
CHARACTERISTICS (TYPICAL)



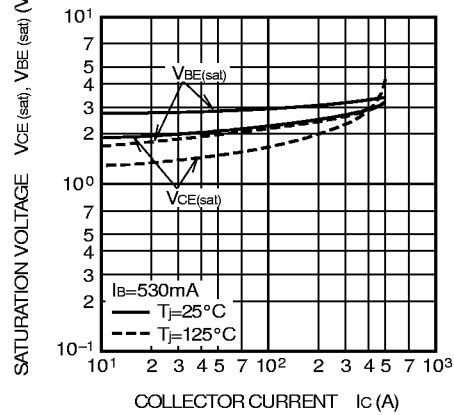
DC CURRENT GAIN VS.
COLLECTOR CURRENT (TYPICAL)



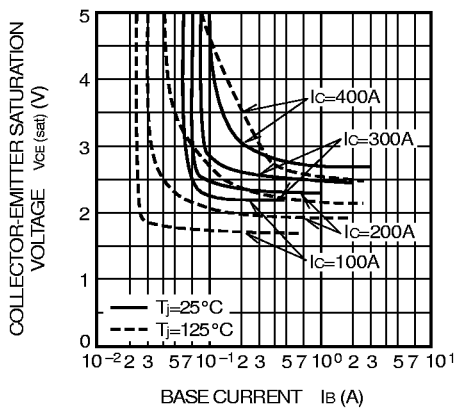
COMMON EMITTER INPUT
CHARACTERISTIC (TYPICAL)



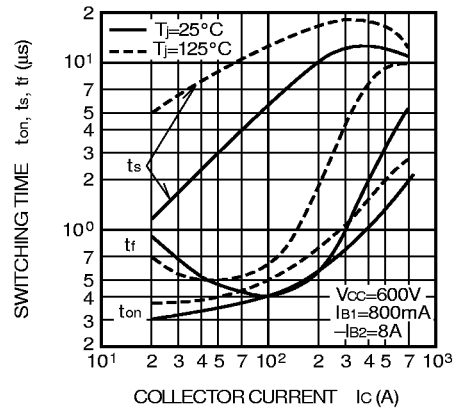
SATURATION VOLTAGE
CHARACTERISTICS (TYPICAL)



COLLECTOR-EMITTER SATURATION
VOLTAGE (TYPICAL)



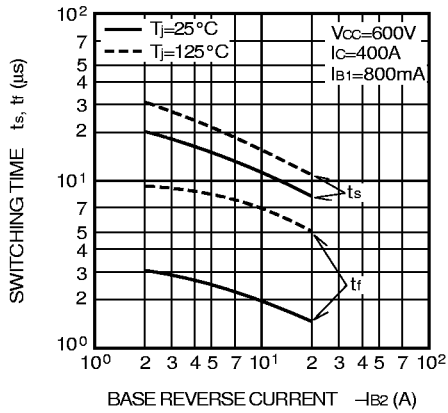
SWITCHING TIME VS. COLLECTOR
CURRENT (TYPICAL)



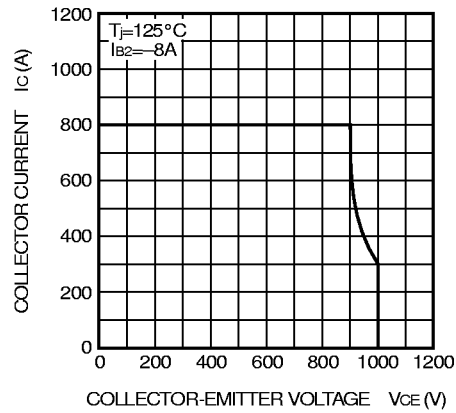
QM400HA-2HB

HIGH POWER SWITCHING USE
INSULATED TYPE

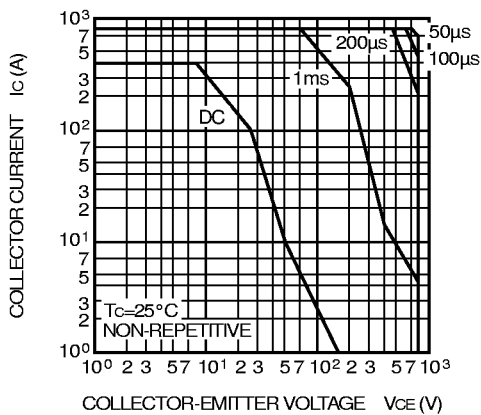
SWITCHING TIME VS. BASE
CURRENT (TYPICAL)



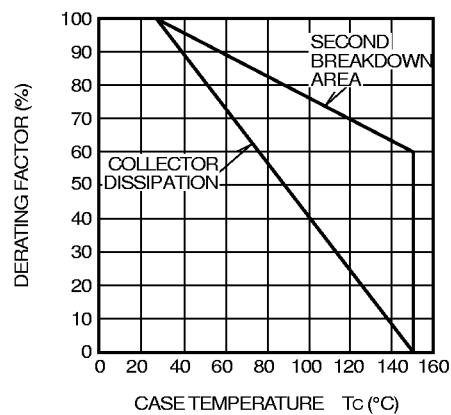
REVERSE BIAS SAFE OPERATING AREA



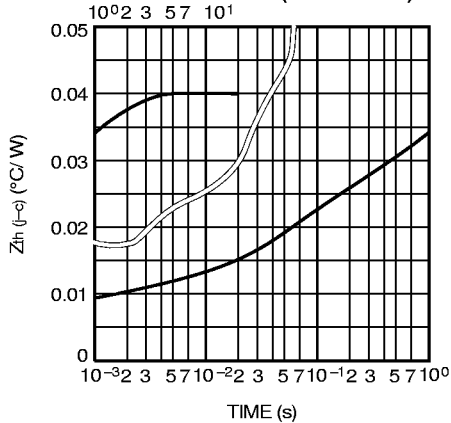
FORWARD BIAS SAFE OPERATING AREA



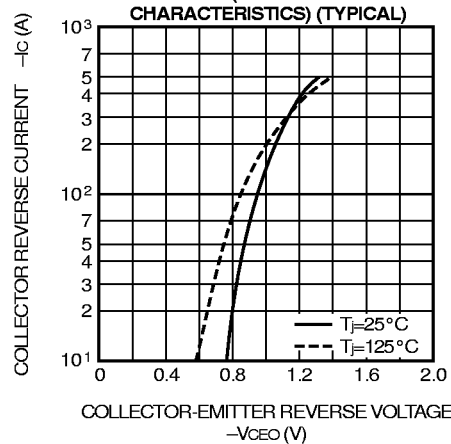
DERATING FACTOR OF F. B. S. O. A.



TRANSIENT THERMAL IMPEDANCE
CHARACTERISTIC (TRANSISTOR)



REVERSE COLLECTOR CURRENT VS.
COLLECTOR-EMITTER REVERSE
VOLTAGE (DIODE FORWARD
CHARACTERISTICS) (TYPICAL)



QM400HA-2HB

HIGH POWER SWITCHING USE
INSULATED TYPE

